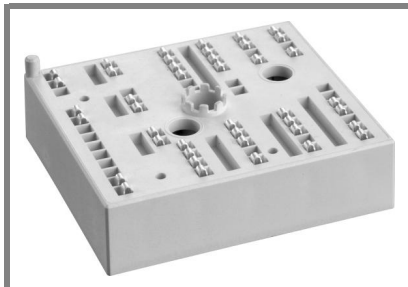


SKiiP 26NAB065V1



MiniSKiiP[®] 2

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter
SKiiP 26NAB065V1

Features

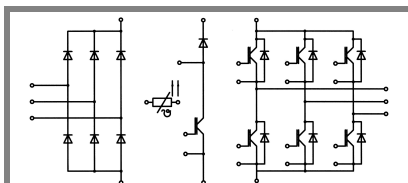
- Ultrafast NPT IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

- Inverter up to 12,5 kVA
- Typical motor power 5,5 kW

Remarks

- V_{CEsat} , V_F = chip level value



NAB

| Absolute Maximum Ratings | | $T_c = 25^\circ\text{C}$, unless otherwise specified | |
|----------------------------------|------------------------------------|---|------------------|
| Symbol | Conditions | Values | Units |
| IGBT - Inverter, Chopper | | | |
| V_{CES} | $T_s = 25 (70)^\circ\text{C}$ | 600 | V |
| I_C | | 56 (42) | A |
| I_{CRM} | | 100 | A |
| V_{GES} | | ± 20 | V |
| T_j | | - 40 ... + 150 | $^\circ\text{C}$ |
| Diode - Inverter, Chopper | | | |
| I_F | $T_s = 25 (70)^\circ\text{C}$ | 40 (30) | A |
| I_{FRM} | | 100 | A |
| T_j | | - 40 ... + 150 | $^\circ\text{C}$ |
| Diode - Rectifier | | | |
| V_{RRM} | $T_s = 70^\circ\text{C}$ | 800 | V |
| I_F | | 61 | A |
| I_{FSM} | | 700 | A |
| i^2t | | $t_p = 10 \text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$ | 2400 |
| T_j | | - 40 ... + 150 | $^\circ\text{C}$ |
| Module | | | |
| I_{RMS} | per power terminal (20 A / spring) | 60 | A |
| T_{stg} | | - 40 ... + 125 | $^\circ\text{C}$ |
| V_{isol} | AC, 1 min. | 2500 | V |

| Characteristics | | $T_c = 25^\circ\text{C}$, unless otherwise specified | | | |
|----------------------------------|--|---|------------|-----------|---------------|
| Symbol | Conditions | min. | typ. | max. | Units |
| IGBT - Inverter, Chopper | | | | | |
| V_{CEsat} | $I_{Cnom} = 50 \text{ A}, T_j = 25 (125)^\circ\text{C}$ | | 2 (2,2) | 2,5 (2,7) | V |
| $V_{GE(th)}$ | $V_{GE} = V_{CE}, I_C = 1 \text{ mA}$ | 3 | 4 | 5 | V |
| $V_{CE(TO)}$ | $T_j = 25 (125)^\circ\text{C}$ | | 1,2 (1,1) | 1,3 (1,2) | V |
| r_T | $T_j = 25 (125)^\circ\text{C}$ | | 16 (22) | 24 (30) | m Ω |
| C_{ies} | $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ | | 2,7 | | nF |
| C_{oes} | $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ | | 0,8 | | nF |
| C_{res} | $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ | | 0,6 | | nF |
| $R_{th(j-s)}$ | per IGBT | | 0,75 | | K/W |
| $t_{d(on)}$ | under following conditions | | 35 | | ns |
| t_r | $V_{CC} = 300 \text{ V}, V_{GE} = \pm 15 \text{ V}$ | | 35 | | ns |
| $t_{d(off)}$ | $I_{Cnom} = 50 \text{ A}, T_j = 125^\circ\text{C}$ | | 240 | | ns |
| t_f | $R_{Gon} = R_{Goff} = 15 \Omega$ | | 25 | | ns |
| E_{on} | inductive load | | 1,3 | | mJ |
| E_{off} | | | 0,9 | | mJ |
| Diode - Inverter, Chopper | | | | | |
| $V_F = V_{EC}$ | $I_{Fnom} = 50 \text{ A}, T_j = 25 (125)^\circ\text{C}$ | | 1,9 (1,9) | 2,3 (2,4) | V |
| $V_{(TO)}$ | $T_j = 25 (125)^\circ\text{C}$ | | 1 (0,9) | 1,1 (1) | V |
| r_T | $T_j = 25 (125)^\circ\text{C}$ | | 18 (20) | 24 (28) | m Ω |
| $R_{th(j-s)}$ | per diode | | 1,5 | | K/W |
| I_{RRM} | under following conditions | | 42 | | A |
| Q_{rr} | $I_{Fnom} = 50 \text{ A}, V_R = 300 \text{ V}$ | | 3,6 | | μC |
| E_{rr} | $V_{GE} = 0 \text{ V}, T_j = 125^\circ\text{C}$ | | 0,8 | | mJ |
| | $di_F/dt = 1500 \text{ A}/\mu\text{s}$ | | | | |
| Diode - Rectifier | | | | | |
| V_F | $I_{Fnom} = 35 \text{ A}, T_j = 25^\circ\text{C}$ | | 1,1 | | V |
| $V_{(TO)}$ | $T_j = 150^\circ\text{C}$ | | 0,8 | | V |
| r_T | $T_j = 150^\circ\text{C}$ | | 11 | | m Ω |
| $R_{th(j-s)}$ | per diode | | 0,9 | | K/W |
| Temperature Sensor | | | | | |
| R_{ts} | 3 %, $T_r = 25 (100)^\circ\text{C}$ | | 1000(1670) | | Ω |
| Mechanical Data | | | | | |
| w | | | 65 | | g |
| M_s | Mounting torque | 2 | | 2,5 | Nm |

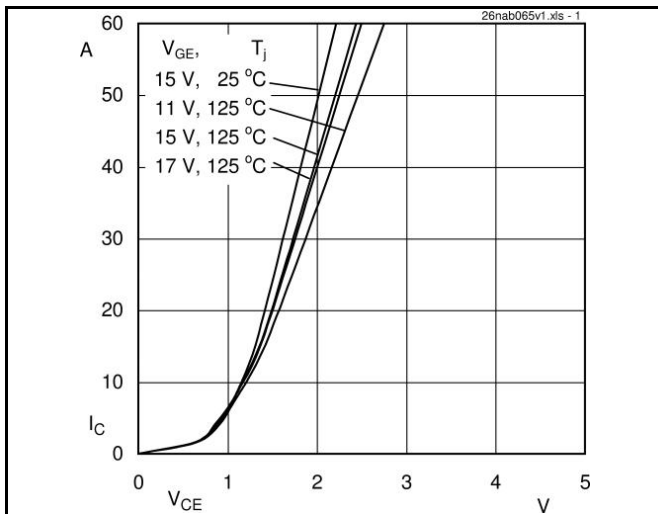


Fig. 1 Typ. output characteristic

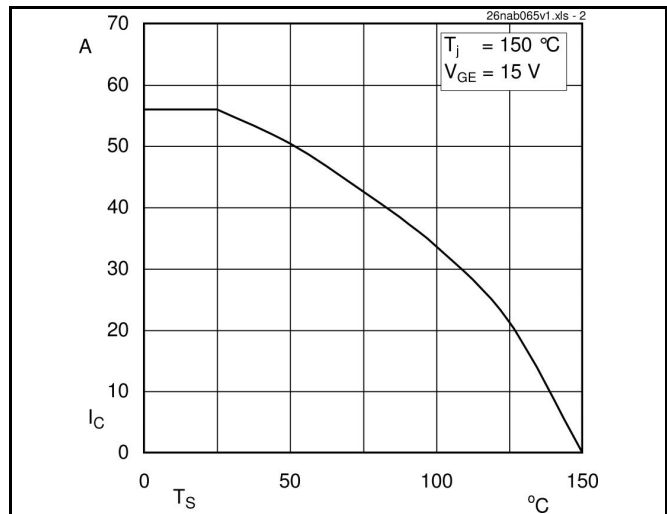


Fig. 2 Typ. rated current vs. temperature

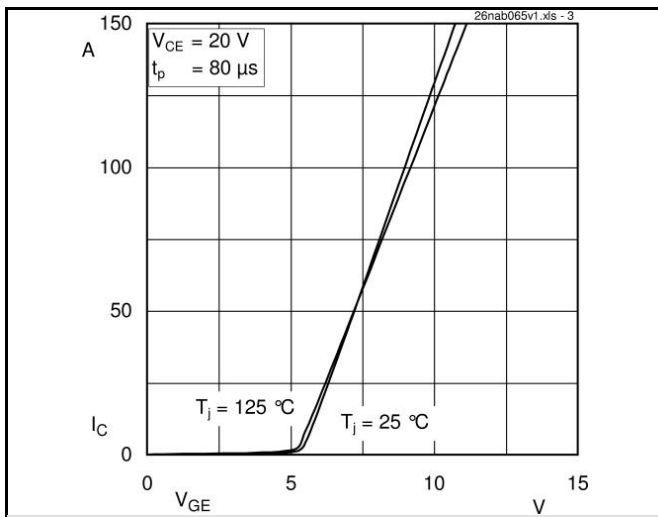


Fig. 3 Typ. transfer characteristic

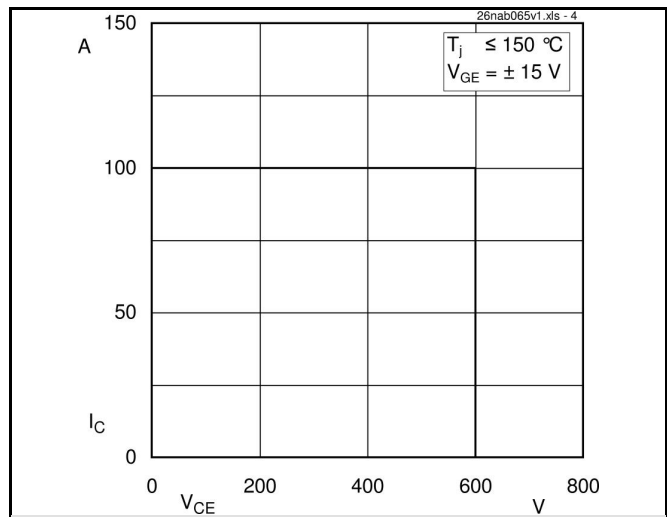


Fig. 4 Reverse bias safe operating area

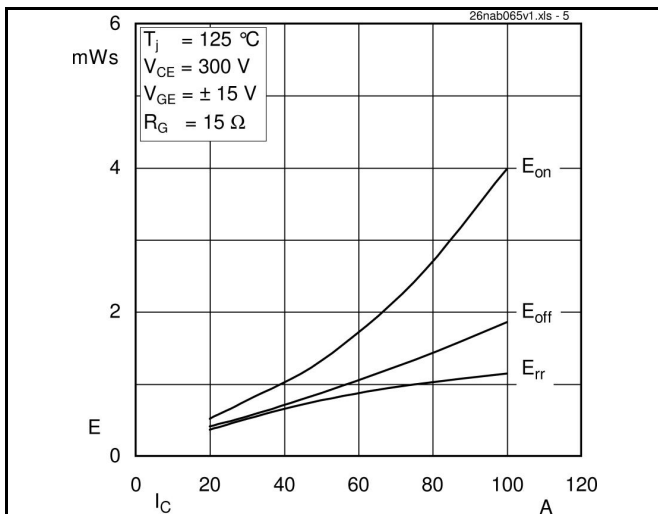


Fig. 5 Typ. Turn-on /-off energy = $f(I_C)$

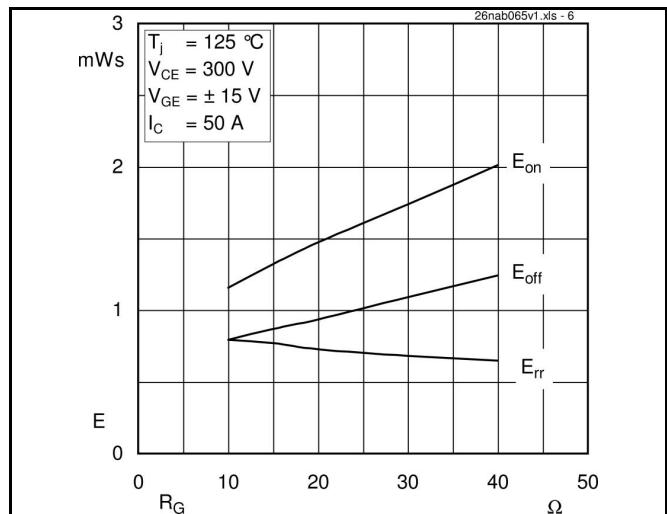
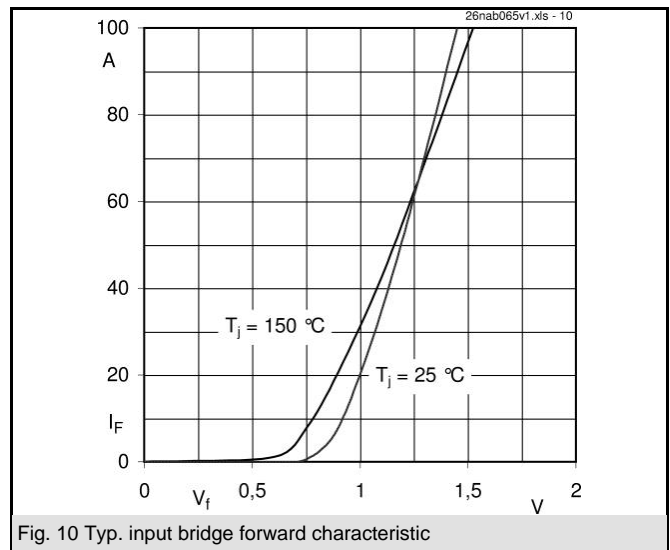
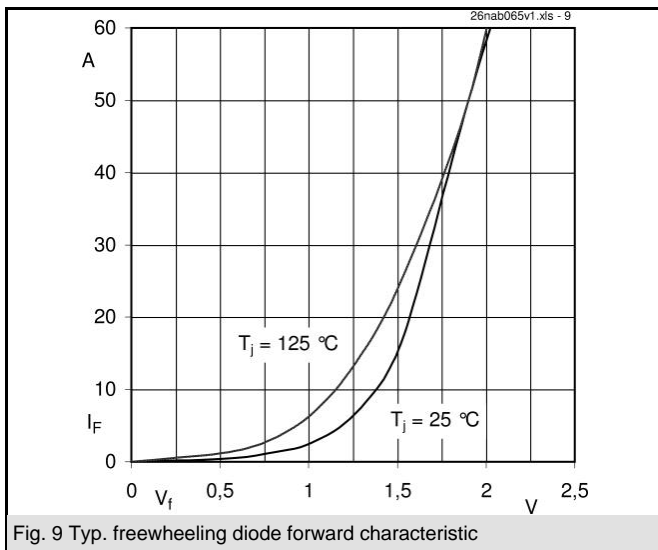
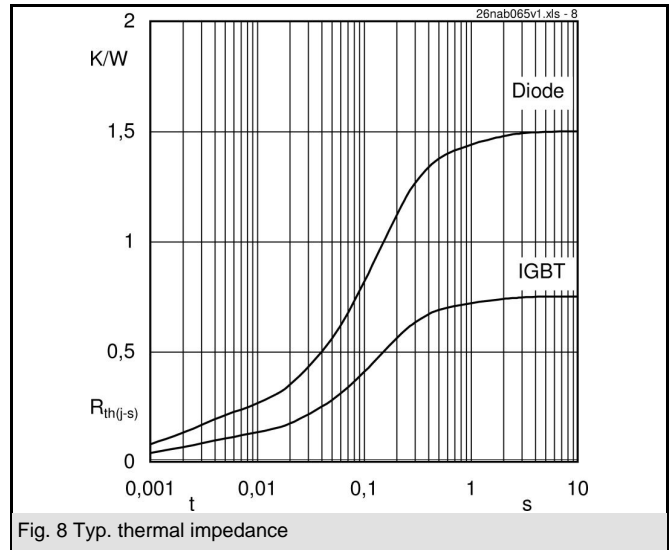
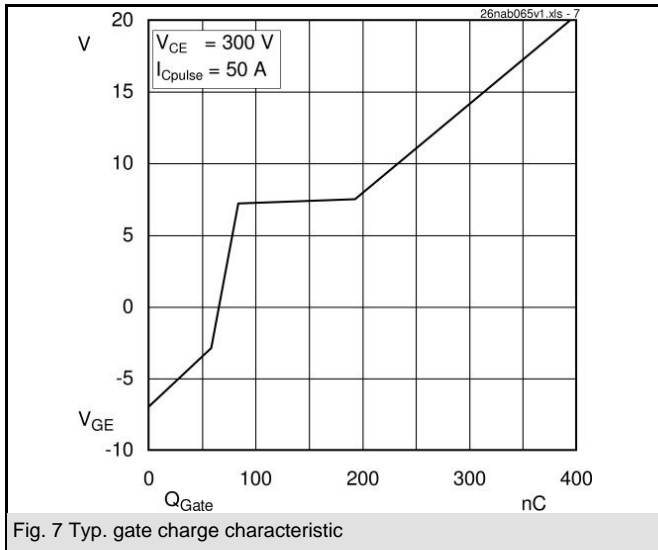
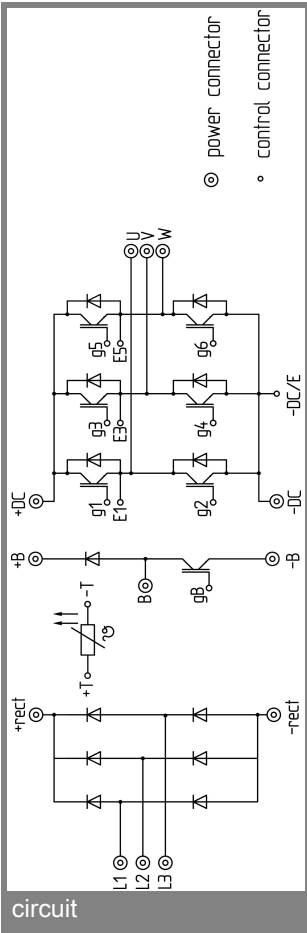
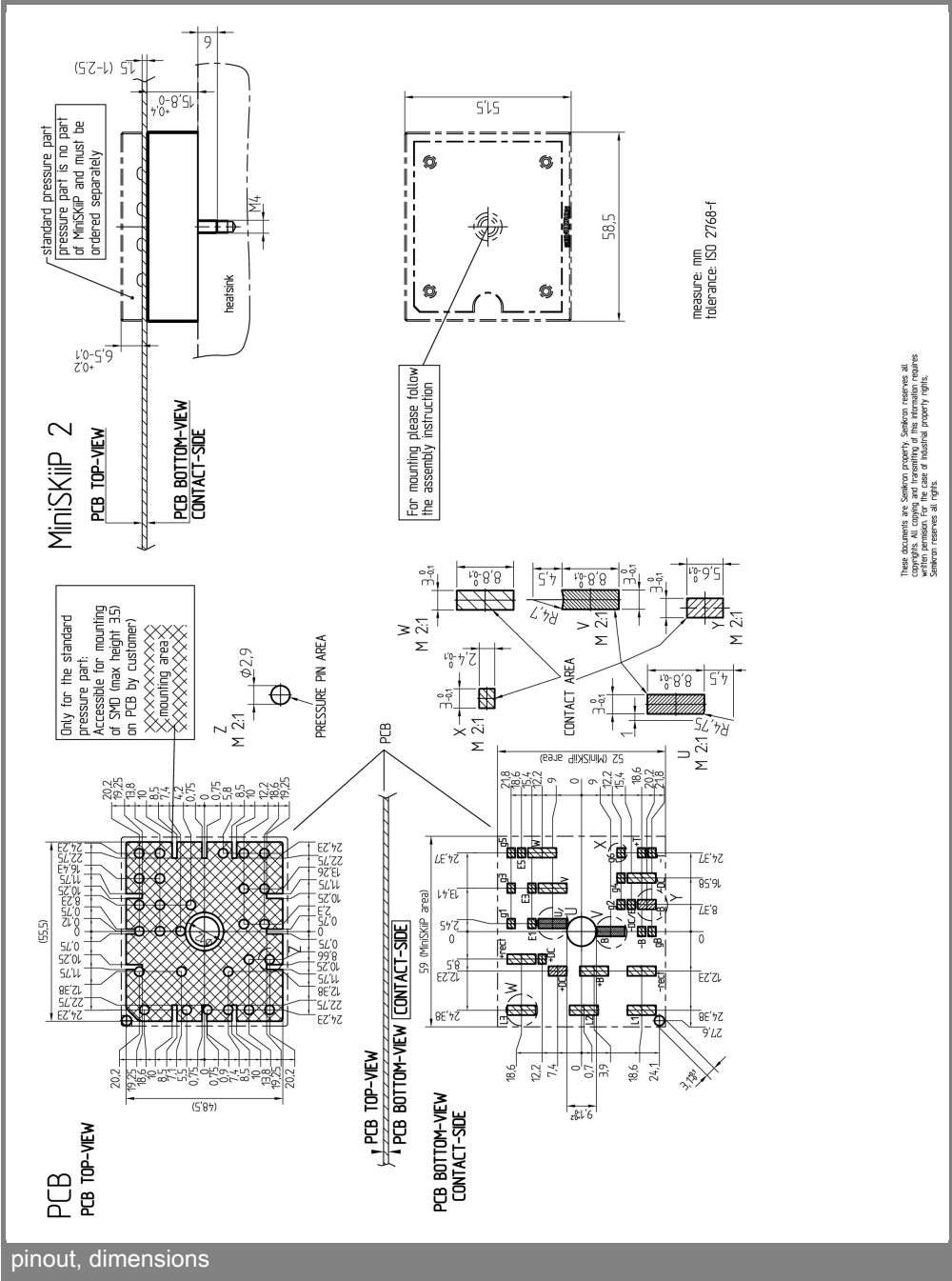


Fig. 6 Typ. Turn-on /-off energy = $f(R_G)$





circuit



pinout, dimensions

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.